

Name: _____

EE303 - Final Exam

Closed Book:

Two 8.5"x11" sheet of handwritten notes permitted

Calculator permitted

Important Notes:

- Read each problem completely and thoroughly
- Summarize all your answers in the boxes provided on these exam sheets
- Make sure to mark the units on your answers!
- Do all your work on the exams sheets provided. If you use any additional sheets, please turn them in, so we can consider all work for partial credit
- Do not forget to put your name in the space above

Problem #	Points	Score
1	10	
2	20	
3	20	
4	20	
5	20	
TOTAL	90	

Unless otherwise specified assume:

NMOS: $\mu_n C_{OX} = 200 \mu A/V^2$ and $V_{THn} = 0.4V$

PMOS: $\mu_p C_{OX} = 100 \mu A/V^2$ and $V_{THp} = -0.4V$

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Problem 1 [10 pts]

Consider the differential pair illustrated in Fig. 10.70. Assuming perfect symmetry and $V_A = \infty$,

- (a) Determine the voltage gain.
- (b) Draw the differential AC half circuit

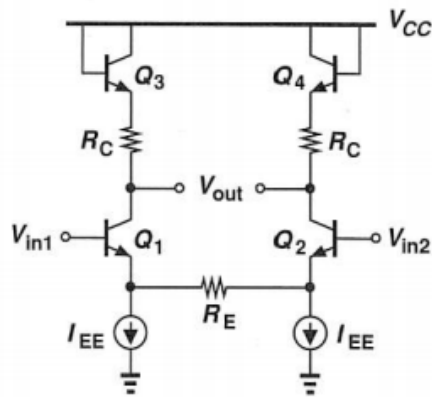


Figure 10.70

$V_{out}/(V_{in1}-V_{in2})$	
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Problem 2 [20 pts]

Calculate the differential voltage gain of the circuits depicted in Fig. 10.76. Assume perfect symmetry and $\lambda > 0$.

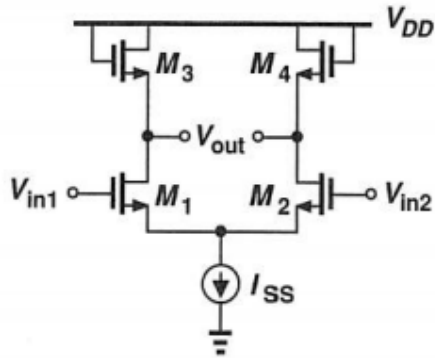


Fig. 10.76 (a)

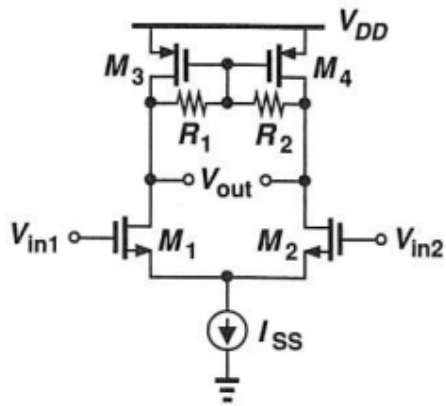


Fig. 10.76 (b)

(a) $V_{out}/(V_{in1}-V_{in2}) =$	
(b) $V_{out}/(V_{in1}-V_{in2}) =$	

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Problem 3 [15 pts]

Calculate I_{copy} in each of the circuits shown in Fig. 9.71. Assume all of the transistors operate in saturation.

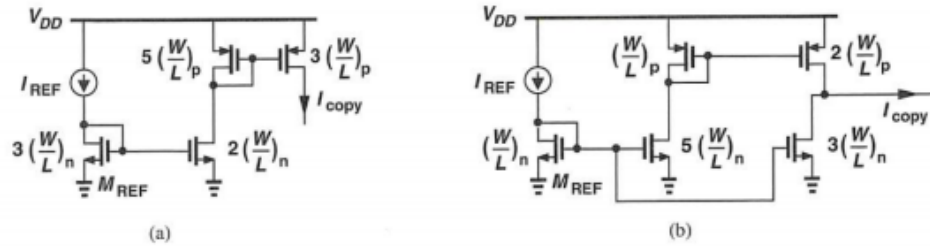


Figure 9.71

a) $I_{copy} =$	
b) $I_{copy} =$	

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Problem 4 [20 pts]

Compute the output resistance of the circuits depicted in Fig. 9.50. Assume all of the transistors operate in saturation and $g_m r_o \gg 1$.

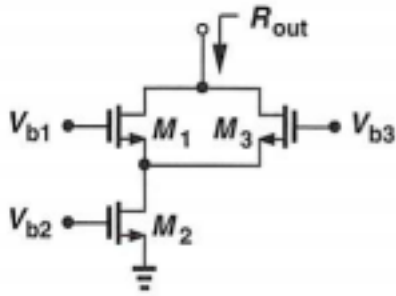


Fig 9.50 (a)

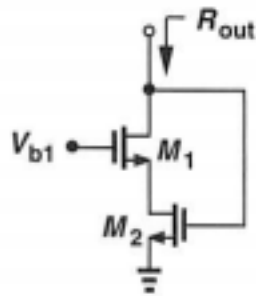


Fig 9.50 (b)

a) $R_{out} =$	
b) $R_{out} =$	

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Problem 5 [10 pts]

Consider the circuit shown in Fig. 9.49, where $V_{DD} = 1.8$ V, $(W/L)_1 = 20/0.18$, and $(W/L)_2 = 40/0.18$. Assume $\mu_n C_{ox} = 100 \mu\text{A}/\text{V}^2$ and $V_{TH} = 0.4$ V.

- (a) If we require a bias current of 1 mA and $R_D = 500 \Omega$, what is the highest allowable value of V_{b1} ?
- (b) With such a value chosen for V_{b1} , what is the value of V_X ?

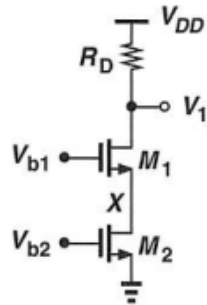


Figure 9.49

(a) $V_{b1}(\text{max}) =$	
(b) $V_X =$	